

# SANYO Semiconductors DATA SHEET

# STK672-432B-E Thick-Film Hybrid IC 2-phase Stepping Motor Driver

## Overview

The STK672-432B-E is a hybrid IC for use as a unipolar, 2-phase stepping motor driver with PWM current control.

## Applications

• Office photocopiers, printers, etc.

## Features

- Built-in motor terminal open detection function (output current OFF).
- Built-in overcurrent detection function (output current OFF).
- Built-in overheat detection function (output current OFF).
- FAULT1 signal (active low) is output when any of motor terminal open, overcurrent, or overheat is detected. The FAULT2 signal is used to output the result of activation of protection circuit detection at 3 levels.
- Built-in power on reset function.
- A micro-step sine wave-driven driver can be activated merely by inputting an external clock.
- External pins can be used to select 2, 1-2 (including pseudo-micro), W1-2, 2 W1-2, or 4W1-2 excitation.
- The switch timing of the 4-phase distributor can be switched by setting an external pin (MODE3) to detect either the rise and fall, or rise only, of CLOCK input.
- Phase is maintained even when the excitation mode is switched. Rotational direction switching function.
- Supports schmitt input for 2.5V high level input.
- Incorporating a current detection resistor (0.152 $\Omega$ : resistor tolerance  $\pm 2\%$ ), motor current can be set using two external resistors.
- The ENABLE pin can be used to cut output current while maintaining the excitation mode.
- With a wide current setting range, power consumption can be reduced during standby.
- No motor sound is generated during hold mode due to external excitation current control.
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# **Specifications**

# Absolute Maximum Ratings at $Tc = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	unit
Maximum supply voltage 1	V <sub>CC</sub> max	No signal	50	V
Maximum supply voltage 2	V <sub>DD</sub> max	No signal	-0.3 to +6.0	V
Input voltage	V <sub>IN</sub> max	Logic input pins	-0.3 to +6.0	V
Output current 1	I <sub>OP</sub> max	10µs, 1 pulse (resistance load)	10	А
Output current 2	I <sub>OH</sub> max	V <sub>DD</sub> =5V, CLOCK≥200Hz	2.5	А
Allowable power dissipation 1	PdMF max	With an arbitrarily large heat sink. Per MOSFET	7.3	W
Allowable power dissipation 2	PdPK max	No heat sink	2.8	W
Operating substrate temperature	Tc max	Metal surface temperature of the package	-20 to +105	°C
Junction temperature	Tj max		150	°C
Storage temperature	Tstg		-40 to +125	°C

## Allowable Operating Ranges at Ta=25°C

Parameter	Symbol	Conditions	Ratings	unit
Operating supply voltage 1	V <sub>CC</sub>	With signals applied	0 to 46	V
Operating supply voltage 2	V <sub>DD</sub>	With signals applied	5±5%	V
Input high voltage	VIH	Pins 10, 11, 12, 13, 14, 15, 17, V <sub>DD</sub> =5±5%	2.5 to V <sub>DD</sub>	V
Input low voltage	VIL	Pins 10, 11, 12, 13, 14, 15, 17, V <sub>DD</sub> =5±5%	0 to 0.8	V
Output current	ЮН	Tc=105°C, CLOCK≥200Hz	2.0	А
CLOCK frequency	fCL	Minimum pulse width: at least 10µs	0 to 50	kHz
Recommended Vref range	Vref		0.14 to 1.48	V

## Electrical Characteristics at Tc=25°C, V<sub>CC</sub>=24V, V<sub>DD</sub>=5.0V \*1

	Parameter	Symbol	Conditions	min	typ	max	unit
V <sub>DD</sub> supply current I <sub>CCO</sub>		Icco	V <sub>DD</sub> =5.0V, ENABLE=Low		5.7	7.0	mA
Output average current *2 loave		loave	R/L=1Ω/0.62mH in each phase	0.19	0.23	0.27	А
FET diode forward voltage Vdf If=1A (RL=23Ω)		1	1.6	V			
Output saturation voltage Vsat		Vsat	R <sub>L</sub> =23Ω		0.35	0.50	V
Control	Input voltage	VIH	Pins 10, 11, 12, 13, 14, 15, 17	2.5		V <sub>DD</sub>	V
input pin		VIL	Pins 10, 11, 12, 13, 14, 15, 17	-0.3		0.8	V
	5V level input current	IILH	Pins 10, 11, 12, 13, 14, 15, 17=5V		50	75	μA
	GND level input current	IILL	Pins 10, 11, 12, 13, 14, 15, 17=GND			10	μA
Vref input bias current IIB		I <sub>IB</sub>	Pin 19 =1.0V			1	μΑ
FAULT1	Output low voltage	VOLF	V <sub>OLF</sub> Pin 16 (I <sub>O</sub> =5mA)		0.25	0.5	V
pin	5V level leakage current	I <sub>ILF</sub>	IILF Pin 16 =5V			10	μΑ
FAULT2 pin	Motor terminal open detection output voltage	V <sub>OF</sub> 1	OF1 Pin 8 (when all protection functions have been activated)		0.01	0.2	
	Overcurrent detection output voltage	V <sub>OF</sub> 2		2.4	2.5	2.6	V
	Overheat detection output voltage	V <sub>OF</sub> 3		3.1	3.3	3.5	
Overheat d	letection temperature	TSD	Design guarantee		144		°C
PWM frequ	iency	fc		41	48	55	kHz
Drain-sour	ce cut-off current	IDSS	V <sub>DS</sub> =100V, Pins 2, 6, 9, 18=GND			1	μA

Notes

\*1: A fixed-voltage power supply must be used.

\*2: The value for Ioave assumes that the lead frame of the product is soldered to the mounting circuit board.

Continued on next page.

# STK672-432B-E

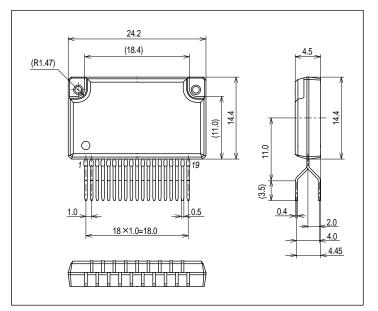
		Paramet	er		Symbol	Conditions	min	typ	max	unit
	4W1-2	2W1-2	W1-2	1-2		<del>θ=</del> 15/16, 16/16		100		
	4W1-2	2W1-2				θ=14/16		97		
	4W1-2					θ=13/16		95		
	4W1-2	2W1-2	W1-2			θ=12/16		93		
0	4W1-2					θ=11/16		87		
Current Ratio	4W1-2	2W1-2			Vref *3	θ=10/16		83		
eut	4W1-2					<del>θ=9/16</del>		77		
LIN'S	4W1-2	2W1-2	W1-2	1-2		θ=8/16		71		%
	4W1-2					θ=7/16		64		%
	4W1-2	2W1-2				θ=6/16		55		
A•B	4W1-2					θ=5/16		47		
	4W1-2	2W1-2	W1-2			<del>0=4</del> /16		40		
	4W1-2					<del>0=</del> 3/16		30		
	4W1-2	2W1-2				θ=2/16		20		
	4W1-2					θ=1/16		11		
		2						100		]

Notes

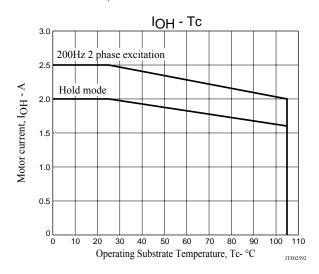
\*3: The values given for Vref are design targets, no measurement is performed.

## **Package Dimensions**

unit:mm (typ)



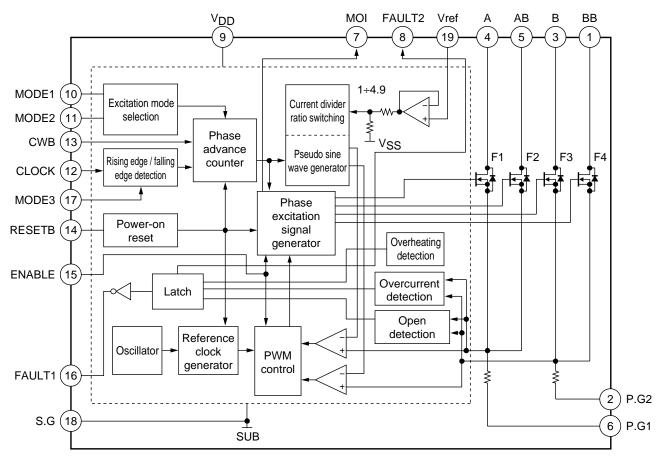
Derating Curve of Motor Current, IOH, vs. STK672-432B-E Operating Substrate Temperature, Tc



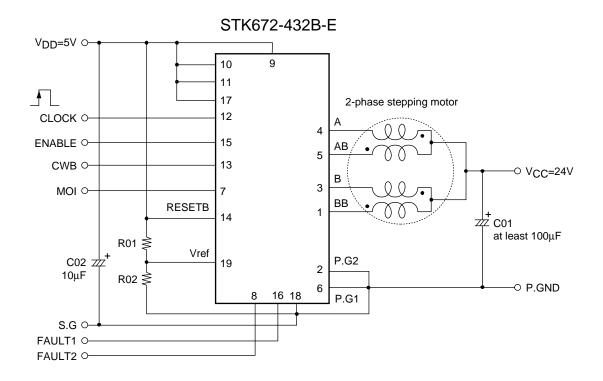
#### Notes

- The current range given above represents conditions when output voltage is not in the avalanche state.
- If the output voltage is in the avalanche state, see the allowable avalanche energy for STK672-4\*\* series hybrid ICs given in a separate document.
- The operating substrate temperature, Tc, given above is measured while the motor is operating. Because Tc varies depending on the ambient temperature, Ta, the value of I<sub>OH</sub>, and the continuous or intermittent operation of I<sub>OH</sub>, always verify this value using an actual set.
- The Tc temperature should be checked in the center of the metal surface of the product package.

## **Block Diagram**



# **Sample Application Circuit**



# Precautions

[GND wiring]

• To reduce noise on the 5V/24V system, be sure to place the GND of C01 in the circuit given above as close as possible to Pin 2 and Pin 6 of the hybrid IC.

In addition, in order to set the current accurately, the GND side of RO2 of Vref must be connected to the shared ground terminal used by the Pin 18 (S.G) GND, P.G1 and P.G2.

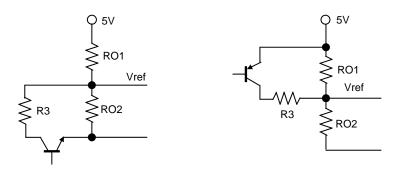
[Input pins]

- If V<sub>DD</sub> is being applied, use care that each input pin does not apply a negative voltage less than -0.3V to S.GND, Pin 18. Measures must also be taken so that a voltage equal to or greater than V<sub>DD</sub> is not input.
- High voltage input other than VDD, MOI, FAULT1, and FAULT2 is 2.5V.
- Pull-up resistors are not connected to input pins. Pull-down resistors are attached. When controlling the input to the hybrid IC with the open collector type, be sure to connect a pull-up resistor (1 to  $20k\Omega$ ). Be sure to use a device (0.8V or less, low level, when IOL=5mA) for the open collector driver at this time that has an output voltage specification such that voltage is pulled to less than 0.8V at low level.
- When using the power on reset function built into the hybrid IC, be sure to directly connect Pin 14 to  $V_{DD}$ .
- We recommend attaching a 1,000pF capacitor to each input to prevent malfunction during high-impedance input. Be sure to connect the capacitor near the hybrid IC, between Pin 18 (S, G).

When input is fixed low, directly connect to Pin 18. When input is fixed high, directly connect to VDD.

[Current setting Vref]

If the motor current is temporarily reduced, the circuit given below is recommended. The variable voltage range of Vref input is 0.14 to 1.48V.



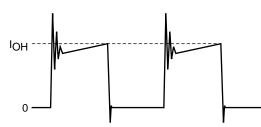
[Setting the motor current]

The motor current, I<sub>OH</sub>, is set using the Pin 19 voltage, Vref, of the hybrid IC. Equations related to I<sub>OH</sub> and Vref are given below.

$Vref \approx (RO2 \div (RO2 + RO1)) \times V_{DD}(5V)$	(1)
$I_{OH} \approx (Vref \div 4.9) \div Rs$	(2)

The value of 4.9 in Equation (2) above represents the Vref voltage as divided by a circuit inside the control IC. Rs:  $0.152\Omega$  (Current detection resistor inside the hybrid IC)

• Motor current peak value IOH setting



[Smoke Emission Precuations]

If Pin 18 (S.G terminal) is attached to the PCB without using solder, overcurrent may flow into the MOSFET at  $V_{CCON}$  (24V ON), to emit smoke because 5V circuits cannot be controlled.

#### **Function Table**

M2	0	0	1	1	CLOCK Edge Timing for
M1 M3	0	1	0	1	Phase Switching
1	2-phase excitation selection	1-2-phase excitation (I <sub>OH</sub> =100%)	W1-2 phase excitation	2W1-2 phase excitation	CLOCK rising edge
0	1-2 phase excitation (I <sub>OH</sub> =100%, 71%)	W1-2 phase excitation	2W1-2 phase excitation	4W1-2 phase excitation	CLOCK both edges

 $I_{\mbox{OH}}{=}100\%$  results in the Vref voltage setting,  $I_{\mbox{OH}}{-}$ 

During 1-2 phase excitation, the hybrid IC operates at a current setting of  $I_{OH}=100\%$  when the CLOCK signal rises. Conversely, pseudo micro current control is performed to control current at  $I_{OH}=100\%$  or 71% at both edges of the CLOCK signal.

## CWB pin

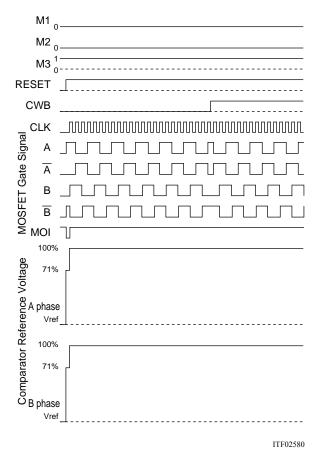
Forward/CW	0
Reverse/CCW	1

## ENABLE • RESETB pin

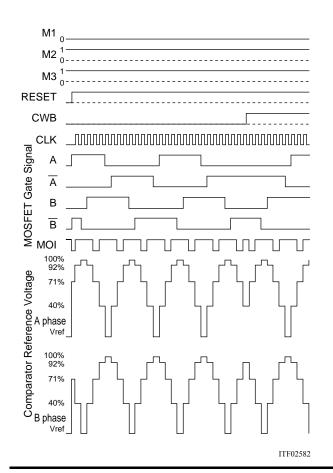
ENABLE	Motor current cut: Low
RESETB	Active Low

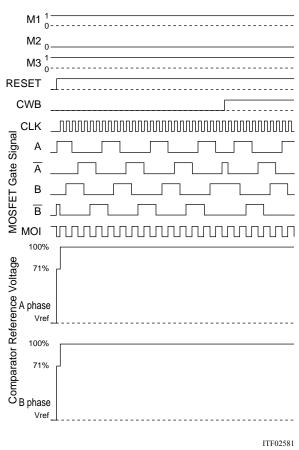
# **Timing Charts**

2-phase excitation timing charts (M3=1)

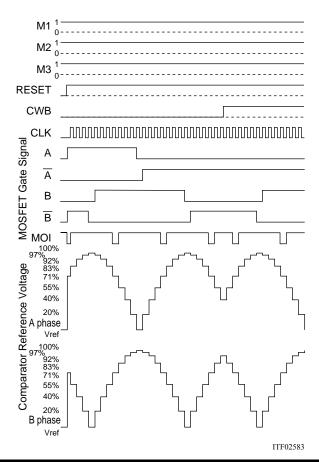


W1-2-phase excitation timing charts (M3=1)



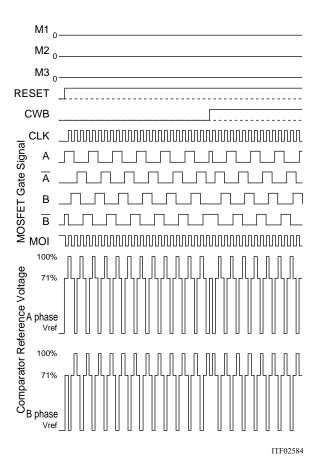


2W1-2-phase excitation timing charts (M3=1)

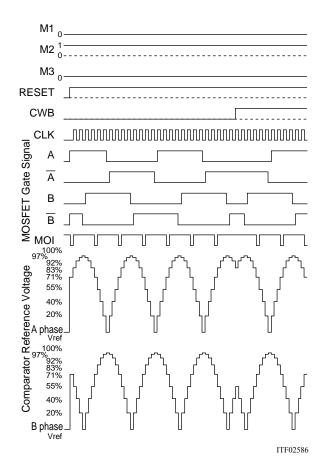


1-2-phase excitation timing charts (M3=1)

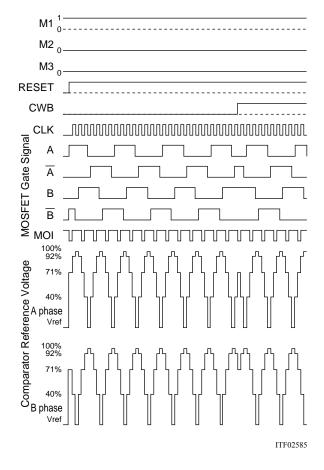
1-2-phase excitation timing charts (M3=0)



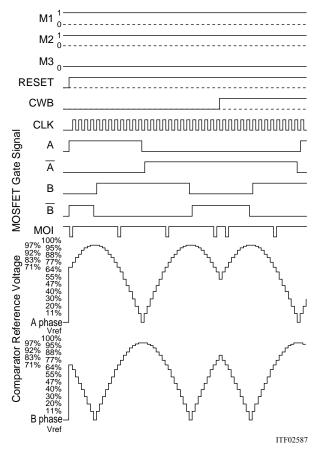
2W1-2-phase excitation timing charts (M3=0)



W1-2-phase excitation timing charts (M3=0)



4W1-2-phase excitation timing charts (M3=0)



## **Usage Notes**

1. I/O Pins and Functions of the Control Block

#### [Pin description]

HIC pin	Pin Name	Function	
7	MOI	Output pin for the excitation monitor	
19	Vref	Current value setting	
10	MODE1		
11	MODE2	Excitation mode selection	
17	MODE3		
12	CLOCK	External CLOCK (motor rotation instruction)	
13	CWB	Sets the direction of rotation of the motor axis	
14	RESETB	System reset	
15	ENABLE	Motor current OFF	
16	FAULT1		
8	FAULT2	Motor terminal open/Overcurrent/over-heat detection output	

## Description of each pin

[CLOCK (Phase switching clock)]

Input frequency: DC-20kHz (when using both edges) or DC-50kHz (when using one edge)

Minimum pulse width: 20µs (when using both edges) or 10µs (when using one edge)

Pulse width duty: 40% to 50%

Both edge, single edge operation

M3:1 The excitation phase moves one step at a time at the rising edge of the CLOCK pulse.

M3:0 The excitation phase moves alternately one step at a time at the rising and falling edges of the CLOCK pulse.

[CWB (Motor direction setting)]

When CWB=0: The motor rotates in the clockwise direction.

When CWB=1: The motor rotates in the counterclockwise direction.

Do not allow CWB input to vary during the 7µs interval before and after the rising and falling edges of CLOCK input.

[ENABLE (Forcible OFF control of excitation drive output A, AB, B, and BB, and selecting operation/hold status inside the HIC)]

ENABLE=1: Normal operation

When ENABLE=0: Motor current goes OFF, and excitation drive output is forcibly turned OFF.

The system clock inside the HIC stops at this time, with no effect on the HIC even if input pins other than RESET input vary. In addition, since current does not flow to the motor, the motor shaft becomes free.

If the CLOCK signal used for motor rotation suddenly stops, the motor shaft may advance beyond the control position due to inertia. A SLOW DOWN setting where the CLOCK cycle gradually decreases is required in order to stop at the control position.

[MODE1, MODE2, and MODE3 (Selecting the excitation mode, and selecting one edge or both edges of the CLOCK)] Excitation select mode terminal (See the sample application circuit for excitation mode selection), selecting the CLOCK input edge(s).

Mode setting active timing

Do not change the mode within  $7\mu s$  of the input rising or falling edge of the CLOCK signal.

## [RESETB (System-wide reset)]

The reset signal is formed by the power-on reset function built into the HIC and the RESETB terminal. When activating the internal circuits of the HIC using the power-on reset signal within the HIC, be sure to connect Pin 14 of the HIC to  $V_{DD}$ .

[Vref (Voltage setting to be used for the current setting reference)]

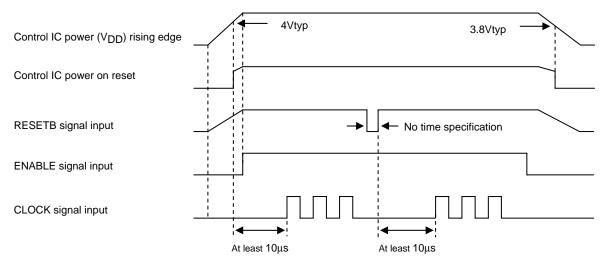
• Pin type: Analog input configuration

Input voltage is in the voltage range of 0.14V to 1.48V.

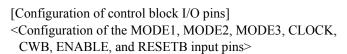
## [Input timing]

The control IC of the driver is equipped with a power on reset function capable of initializing internal IC operations when power is supplied. A 4V typ setting is used for power on reset. Because the specification for the MOSFET gate voltage is  $5V\pm5\%$ , conduction of current to output at the time of power on reset adds electromotive stress to the MOSFET due to lack of gate voltage. To prevent electromotive stress, be sure to set ENABLE=Low while V<sub>DD</sub>, which is outside the operating supply voltage, is less than 4.75V.

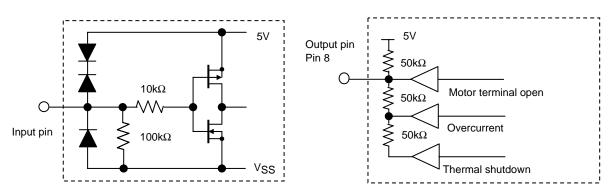
In addition, if the RESETB terminal is used to initialize output timing, be sure to allow at least 10µs until CLOCK input.



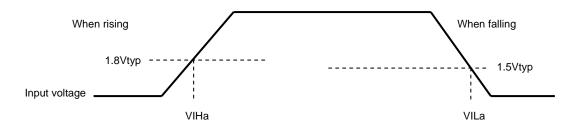
ENABLE, CLOCK, and RESETB Signals Input Timing



<Configuration of the FAULT2 pin>

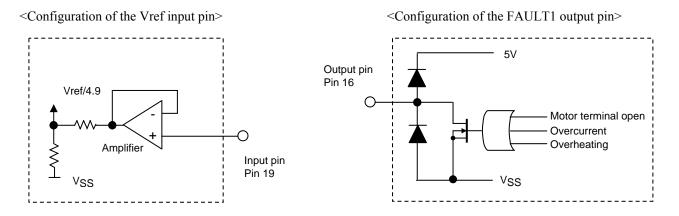


The input pins of this driver all use Schmitt input. Typical specifications at Tc=25°C are given below. Hysteresis voltage is 0.3V (VIHa-VILa).



Input voltage specifications are as follows.  $V_{IH}=2.5Vmin$ 

V<sub>IL</sub>=0.8Vmax



## <FAULT1, FAULT2 output>

#### FAULT1 Output

• FAULT1 is an open drain output. It outputs low level when any of motor terminal open, overcurrent, or overheat is detected.

## FAULT2 output

Output is resistance divided (3 levels) and the type of abnormality detected is converted to the corresponding output voltage.

- Motor terminal open: 10mV (typ)
- Overcurrent: 2.5V (typ)
- Overheat: 3.3V (typ)

Abnormality detection can be released by a RESETB operation or turning VDD voltage on/off.

## [MOI output]

The output frequency of this excitation monitor pin varies depending on the excitation mode. For output operations, see the timing chart.

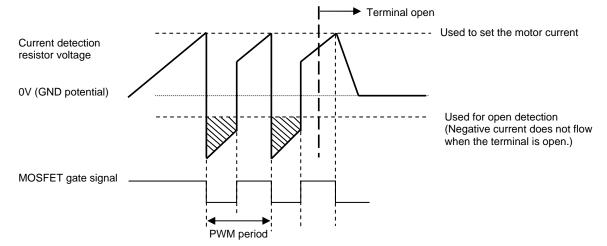
2. STK672-422B-E/432B-E/442B-E/440B-E motor terminal open detection, overcurrent detection, and overheat detection functions

Each detection function operates using a latch system and turns output off. Because a RESET signal is required to restore output operations, once the power supply,  $V_{DD}$ , is turned off, you must either again apply power on reset with  $V_{DD}ON$  or apply a RESETB=High $\rightarrow$ Low $\rightarrow$ High signal.

[Motor terminal open detection]

This hybrid IC is equipped with a function for detecting open output terminals to prevent thermal destruction of the MOSFET due to repeated avalanche operation that occurs when an output terminal connected to the motor is open. The open condition is determined by checking the presence or absence of the flyback current that flows in the motor inductance during the off period of the PWM cycle.

Detection is performed by using the fact that the flyback current does not flow when a motor terminal is open.

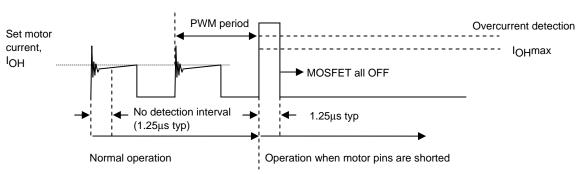


When the current level drops, the voltage difference with the GND potential becomes smaller, making detection difficult. The motor currents that can be detected by motor terminal open detection are 0.6A or more with the STK672-422B-E, 0.9A or more with the STK672-432B-E, and 1.1A or more with the STK672-442B-E/440B-E.

## [Overcurrent detection]

This hybrid IC is equipped with a function for detecting overcurrent that arises when the motor burns out or when there is a short between the motor terminals.

Overcurrent detection occurs at 2.3A typ with the STK672-422B-E, 3.4A typ with the STK672-432B-E, and 5.0A typ with the STK672-442B-E.



Current when motor terminals are shorted

Overcurrent detection begins after an interval of no detection (a dead time of 1.25µs typ) during the initial ringing part during PWM operations. The no detection interval is a period of time where overcurrent is not detected even if the current exceeds I<sub>OH</sub>.

[Overheat detection]

Rather than directly detecting the temperature of the semiconductor device, overheat detection detects the temperature of the aluminum substrate (144°C typ).

Within the allowed operating range recommended in the specification manual, if a heat sink attached for the purpose of reducing the operating substrate temperature, Tc, comes loose, the semiconductor can operate without breaking. However, we cannot guarantee operations without breaking in the case of operations other than those recommended, such as operations at a current exceeding I<sub>OH</sub> max that occurs before overcurrent detection is activated.

## 3. STK672-432B-E Allowable Avalanche Energy Value

(1) Allowable Range in Avalanche Mode

When driving a 2-phase stepping motor with constant current chopping using an STK672-4\*\* Series hybrid IC, the waveforms shown in Figure 1 below result for the output current, ID, and voltage, VDS.

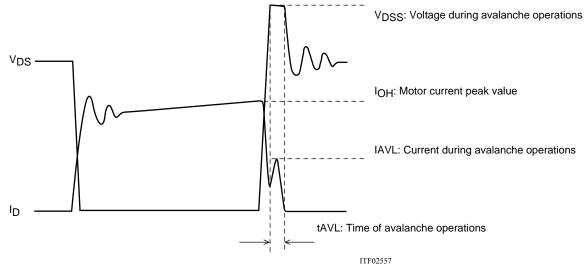


Figure 1 Output Current, I<sub>D</sub>, and Voltage, V<sub>DS</sub>, Waveforms 1 of the STK672-4\*\* Series when Driving a 2-Phase Stepping Motor with Constant Current Chopping

When operations of the MOSFET built into STK672-4\*\* Series ICs is turned off for constant current chopping, the I<sub>D</sub> signal falls like the waveform shown in the figure above. At this time, the output voltage,  $V_{DS}$ , suddenly rises due to electromagnetic induction generated by the motor coil.

In the case of voltage that rises suddenly, voltage is restricted by the MOSFET V<sub>DSS</sub>. Voltage restriction by V<sub>DSS</sub> results in a MOSFET avalanche. During avalanche operations, I<sub>D</sub> flows and the instantaneous energy at this time, EAVL1, is represented by Equation (3-1).

During STK672-4\*\* Series operations, the waveforms in the figure above repeat due to the constant current chopping operation. The allowable avalanche energy, EAVL, is therefore represented by Equation (3-2) used to find the average power loss, PAVL, during avalanche mode multiplied by the chopping frequency in Equation (3-1).

PAVL=V<sub>DSS</sub>×IAVL×0.5×tAVL×fc ------(3-2) fc: Hz units (fc is set to the PWM frequency of 50kHz.)

For V<sub>DSS</sub>, IAVL, and tAVL, be sure to actually operate the STK672-4\*\* Series and substitute values when operations are observed using an oscilloscope.

Ex. If V<sub>DSS</sub>=110V, IAVL=1A, tAVL=0.2µs when using a STK672-432B-E driver, the result is: PAVL=110×1×0.5×0.2×10<sup>-6</sup>×50×10<sup>3</sup>=0.55W

VDSS=110V is a value actually measured using an oscilloscope.

The allowable loss range for the allowable avalanche energy value, PAVL, is shown in the graph in Figure 3. When examining the avalanche energy, be sure to actually drive a motor and observe the I<sub>D</sub>,  $V_{DSS}$ , and tAVL waveforms during operation, and then check that the result of calculating Equation (3-2) falls within the allowable range for avalanche operations.

(2) ID and VDSS Operating Waveforms in Non-avalanche Mode

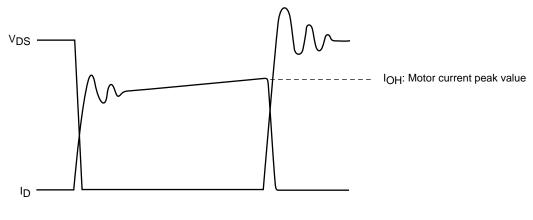
Although the waveforms during avalanche mode are given in Figure 1, sometimes an avalanche does not result during actual operations.

Factors causing avalanche are listed below.

- Poor coupling of the motor's phase coils (electromagnetic coupling of A phase and AB phase, B phase and BB phase).
- Increase in the lead inductance of the harness caused by the circuit pattern of the P.C. board and motor.

• Increases in V<sub>DSS</sub>, tAVL, and IAVL in Figure 1 due to an increase in the supply voltage from 24V to 36V. If the factors above are negligible, the waveforms shown in Figure 1 become waveforms without avalanche as shown in Figure 2.

Under operations shown in Figure 2, avalanche does not occur and there is no need to consider the allowable loss range of PAVL shown in Figure 3.



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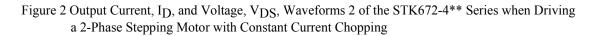
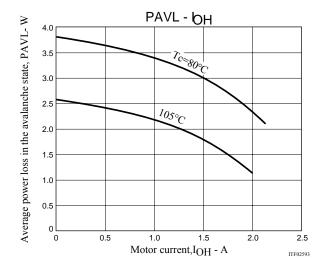


Figure 3 Allowable Loss Range, PAVL-IOH During STK672-432B-E Avalanche Operations



Note:

The operating conditions given above represent a loss when driving a 2-phase stepping motor with constant current chopping.

Because it is possible to apply 2.6W or more at I<sub>OH</sub>=0A, be sure to avoid using the MOSFET body diode that is used to drive the motor as a zener diode.

#### 4. Calculating STK672-432B-E HIC Internal Power Loss

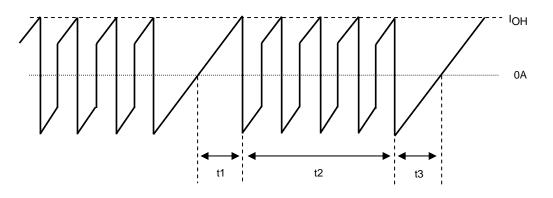
The average internal power loss in each excitation mode of the STK672-432B-E can be calculated from the following formulas. \*1

[Each excitation mode] 2-phase excitation mode 2PdAVex= 2×Vsat×0.5×CLOCK×I <sub>OH</sub> ×t2+0.5×CLOCK×I <sub>OH</sub> × (Vsat×t1+Vdf×t3) (4-1)
1-2 Phase excitation mode 1-2PdAVex= 2×Vsat×0.25×CLOCK×I <sub>OH</sub> ×t2+0.25×CLOCK×I <sub>OH</sub> × (Vsat×t1+Vdf×t3) (4-2)
W1-2 Phase excitation mode W1-2PdAVex=0.64[2×Vsat×0.125×CLOCK×I <sub>OH</sub> ×t2+0.125×CLOCK×I <sub>OH</sub> × (Vsat×t1+Vdf×t3)] (4-3)
2W1-2 Phase excitation mode 2W1-2PdAVex=0.64[2×Vsat×0.0625×CLOCK×I <sub>OH</sub> ×t2+0.0625×CLOCK×I <sub>OH</sub> ×(Vsat×t1+Vdf×t3)] (4-4)
4W1-2 Phase excitation mode 4W1-2PdAVex=0.64[2×Vsat×0.0625×CLOCK×I <sub>OH</sub> ×t2+0.0625×CLOCK×I <sub>OH</sub> ×(Vsat×t1+Vdf×t3)] (4-5)
Motor hold mode HoldPdAVex= 2×Vsat×I <sub>OH</sub>
t1 t2 and t3 represent the waveforms shown in the figure below

t1, t2, and t3 represent the waveforms shown in the figure below.

t1: Time required for the winding current to reach the set current (IOH)

- t2: Time in the constant current control (PWM) region
- t3: Time from end of phase input signal until inverse current regeneration is complete



Motor COM Current Waveform Model

$t1 = (-L/(R+0.35)) In (1-(((R+0.35)/V_{CC}) \times I_{OH}))$	· (4-7)
$t3 = (-L/R) \ln ((V_{CC}+0.35)/(I_{OH}\times R+V_{CC}+0.35))$	(4-8)
V <sub>CC</sub> : Motor supply voltage (V)	
L: Motor inductance (H)	
R: Motor winding resistance ( $\Omega$ )	
IOH: Motor set output current crest value (A)	

Fixed current control time, t2, for each excitation mode	
(1) 2-phase excitation	$t2 = (2 \div CLOCK) - (t1 + t3) \cdots (4-9)$
(2) 1-2 phase excitation	$t2 = (3 \div CLOCK) - t1$ (4-10)
(3) W1-2 phase excitation	$t2 = (7 \div CLOCK) - t1$ (4-11)
(4) 2W1-2 phase excitation (and 4W1-2 phase excitation)	$t2 = (15 \div CLOCK) - t1$ (4-12)

For the values of Vsat and Vdf, be sure to substitute from Vsat vs IOH and Vdf vs IOH at the setting current value IOH. (See pages to follow)

Then, determine if a heat sink is necessary by comparing with the  $\Delta Tc$  vs Pd graph (see next page) based on the calculated average output loss, HIC.

For heat sink design, be sure to see STK672-432B-E.

The HIC average power, PdAVex described above, represents loss when not in avalanche mode. To add the loss in avalanche mode, be sure to add PAVL (4-13, 14) using the formula (3-2) for average power loss, PAVL, for STK672-4\*\* avalanche mode, described below to PdAVex described above.

When using this IC without a fin, always check for temperature increases in the set, because the HIC substrate temperature, Tc, varies due to effects of convection around the HIC.

[Calculating the average power loss, PAVL, during avalanche mode]

The allowable avalanche energy, EAVL, during fixed current chopping operation is represented by Equation (3-2) used to find the average power loss, PAVL, during avalanche mode that is calculated by multiplying Equation (3-1) by the chopping frequency.

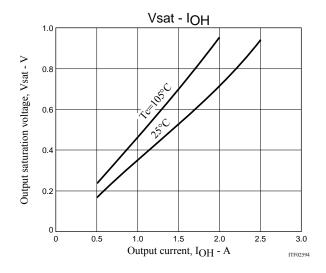
PAVL=V<sub>DSS</sub>×IAVL×0.5×tAVL×fc······(3-2)

fc: Hz units (input MAX PWM frequency when using the STK672-4\*\* series.)

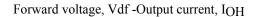
Be sure to actually operate an STK672-4\*\* series and substitute values found when observing operations on an oscilloscope for  $V_{DSS}$ , IAVL, and tAVL.

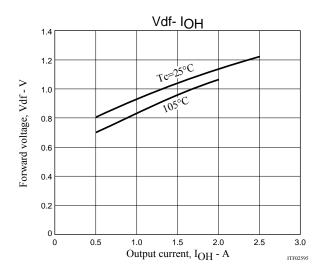
The sum of PAVL values for each excitation mode is multiplied by the constants given below and added to the average internal HIC loss equation, except in the case of 2-phase excitation.

1-2 excitation mode and higher: PAVL(1)=0.7×PAVL (4-13)	)
During 2-phase excitation and motor hold: PAVL(1)=1×PAVL(4-14)	)

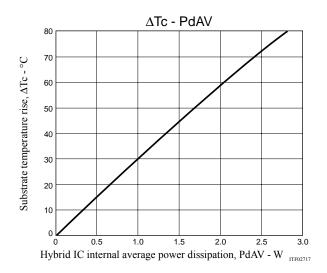


Output saturation voltage, Vsat - Output current, IOH





Substrate temperature rise,  $\Delta Tc$  (no heat sink) - Internal average power dissipation, PdAV



## 5. Thermal design

[Operating range in which a heat sink is not used]

Use of a heat sink to lower the operating substrate temperature of the HIC (Hybrid IC) is effective in increasing the quality of the HIC.

The size of heat sink for the HIC varies depending on the magnitude of the average power loss, PdAV, within the HIC. The value of PdAV increases as the output current increases. To calculate PdAV, refer to "Calculating Internal HIC Loss for the STK672-432B-E".

Calculate the internal HIC loss, PdAV, assuming repeat operation such as shown in Figure 1 below, since conduction during motor rotation and off time both exist during actual motor operations,

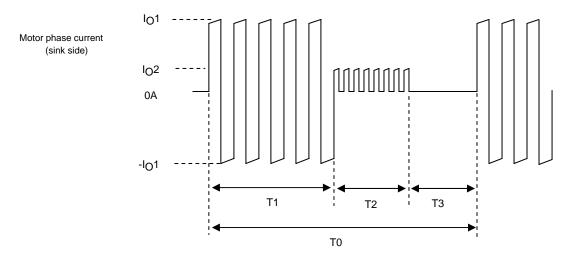


Figure 1 Motor Current Timing

T1: Motor rotation operation time

T2: Motor hold operation time

T3: Motor current off time

T2 may be reduced, depending on the application.

T0: Single repeated motor operating cycle

IO1 and IO2: Motor current peak values

Due to the structure of motor windings, the phase current is a positive and negative current with a pulse form. Note that figure 1 presents the concepts here, and that the on/off duty of the actual signals will differ.

The hybrid IC internal average power dissipation PdAV can be calculated from the following formula.

$$PdAV = (T1 \times P1 + T2 \times P2 + T3 \times 0) \div TO -----(I)$$

(Here, P1 is the PdAV for IO1 and P2 is the PdAV for IO2)

If the value calculated using Equation (I) is 1.5W or less, and the ambient temperature, Ta, is  $60^{\circ}C$  or less, there is no need to attach a heat sink. Refer to Figure 2 for operating substrate temperature data when no heat sink is used.

#### [Operating range in which a heat sink is used]

Although a heat sink is attached to lower Tc if PdAV increases, the resulting size can be found using the value of  $\theta$ c-a in Equation (II) below and the graph depicted in Figure 3.

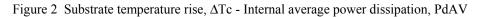
 $\theta c-a = (Tc max-Ta) \div PdAV -----(II)$ 

Tc max: Maximum operating substrate temperature = $105^{\circ}C$ 

Ta: HIC ambient temperature

Although a heat sink can be designed based on equations (I) and (II) above, be sure to mount the HIC in a set and confirm that the substrate temperature, Tc, is 105°C or less.

The average HIC power loss, PdAV, described above represents the power loss when there is no avalanche operation. To add the loss during avalanche operations, be sure to add Equation (3-2), "Allowable STK672-4\*\* Avalanche Energy Value", to PdAV.



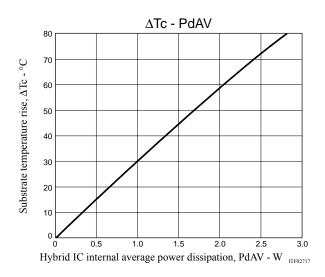
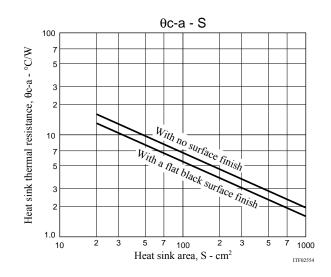


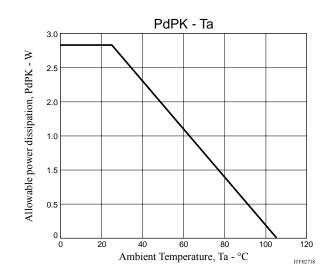
Figure 3 Heat sink area (Board thickness: 2mm) -  $\theta$ c-a



6. Mitigated Curve of Package Power Loss, PdPK, vs. Ambient Temperature, Ta

Package power loss, PdPK, refers to the average internal power loss, PdAV, allowable without a heat sink. The figure below represents the allowable power loss, PdPK, vs. fluctuations in the ambient temperature, Ta. Power loss of up to 2.8W is allowable at Ta=25°C, and of up to 1.5W at Ta=60°C. \* The package thermal resistance  $\theta$ c-a is 28.6°C/W.

Allowable power dissipation, PdPK (no heat sink) - Ambient temperature, Ta



## 7. Other Notes on Use

In addition to the "Notes" indicated in the Sample Application Circuit, care should also be given to the following contents during use.

(1) Allowable operating range

Operation of this product assumes use within the allowable operating range. If a supply voltage or an input voltage outside the allowable operating range is applied, an overvoltage may damage the internal control IC or the MOSFET.

If a voltage application mode that exceeds the allowable operating range is anticipated, connect a fuse or take other measures to cut off power supply to the product.

(2) Input pins

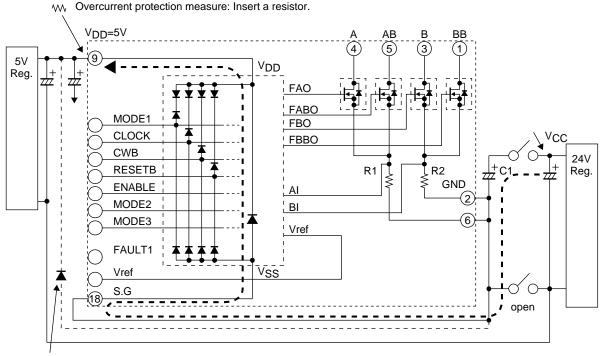
If the input pins are connected directly to the PC board connectors, electrostatic discharge or other overvoltage outside the specified range may be applied from the connectors and may damage the product. Current generated by this overvoltage can be suppressed to effectively prevent damage by inserting  $100\Omega$  to  $1k\Omega$  resistors in lines connected to the input pins.

Take measures such as inserting resistors in lines connected to the input pins.

(3) Power connectors

If the motor power supply  $V_{CC}$  is applied by mistake without connecting the GND part of the power connector when the product is operated, such as for test purposes, an overcurrent flows through the  $V_{CC}$  decoupling capacitor, C1, to the parasitic diode between the  $V_{DD}$  of the internal control IC and GND, and may damage the power supply pin block of the internal control IC.

To prevent damage in this case, connect a  $10\Omega$  resistor to the V<sub>DD</sub> pin, or insert a diode between the V<sub>CC</sub> decoupling capacitor C1 GND and the V<sub>DD</sub> pin.

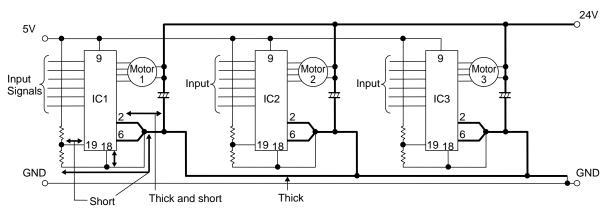


Overcurrent protection measure: Insert a diode.

- - - Over-current path

- (4) Input Signal Lines
  - 1) Do not use an IC socket to mount the driver, and instead solder the driver directly to the PC board to minimize fluctuations in the GND potential due to the influence of the resistance component and inductance component of the GND pattern wiring.
  - 2) To reduce noise caused by electromagnetic induction to small signal lines, do not design small signal lines (sensor signal lines, and 5V or 3.3V power supply signal lines) that run parallel in close proximity to the motor output line A (Pin 4), AB (Pin 5), B (Pin 3), or BB (Pin 1) phases.

(5) When mounting multiple drivers on a single PC board When mounting multiple drivers on a single PC board, the GND design should mount a V<sub>CC</sub> decoupling capacitor, C1, for each driver to stabilize the GND potential of the other drivers. The key wiring points are as follows.



#### (6) V<sub>CC</sub> operating limit

When the output (for example F1) of a 2-phase stepping motor driver is turned OFF, the AB phase back electromotive force eab produced by current flowing to the paired F2 parasitic diode is induced in the F1 side, causing the output voltage VFB to become twice or more the V<sub>CC</sub> voltage. This is expressed by the following formula.

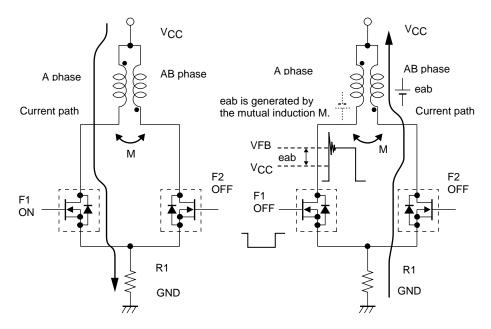
$$VFB = V_{CC} + eab$$

 $= V_{CC} + V_{CC} + I_{OH} \times RM + Vdf (1.5 V)$ 

VCC: Motor supply voltage, IOH: Motor current set by Vref

Vdf: Voltage drop due to F2 parasitic diode and current detection resistor R1, RM: Motor winding resistance value

Using the above formula, make sure that VFB is always less than the MOSFET withstand voltage of 100V. This is because there is a possibility that operating limit of  $V_{CC}$  falls below the allowable operating range of 46V, due to the RM and I<sub>OH</sub> specifications.



The oscillating voltage in excess of VFB is caused by LCRM (inductance, capacitor, resistor, mutual inductance) oscillation that includes micro capacitors C, not present in the circuit. Since M is affected by the motor characteristics, there is some difference in oscillating voltage according to the motor specifications. In addition, constant voltage drive without constant current drive enables motor rotation at  $V_{CC} \ge 0V$ .

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